Eastern Economy Edition

Principles of ELECTRONICS

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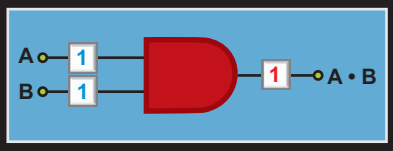

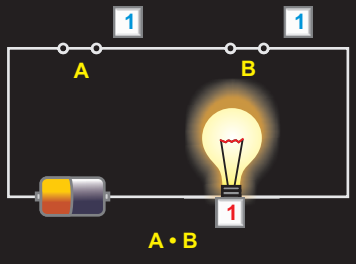

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Principles of Electronics

PRINCIPLES OF
ELECTRONICS

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PRINCIPLES OF ELECTRONICS
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To

My grandchildren

VANSHIKA AND AHILAAN

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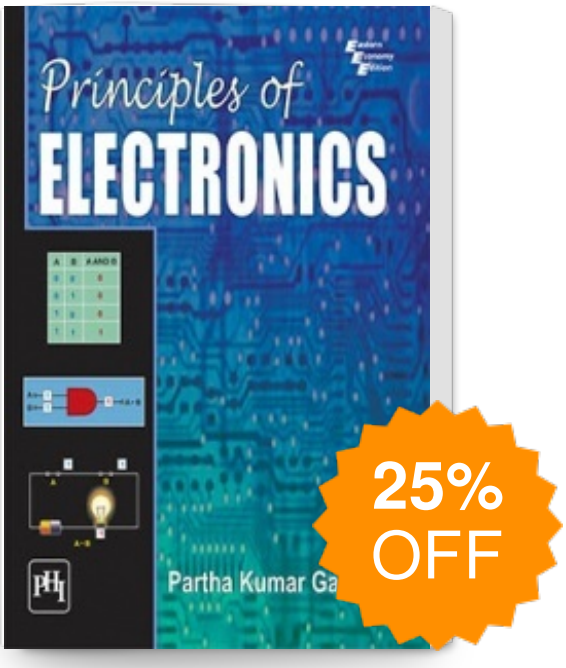

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